



TSM4410

Preliminary

N-Channel Enhancement Mode MOSFET

SOP-8



Pin assignment:

1. Source
2. Source
3. Source
4. Gate
- 5, 6, 7, 8. Drain

$V_{DS} = 25V$

$I_D = 10A$

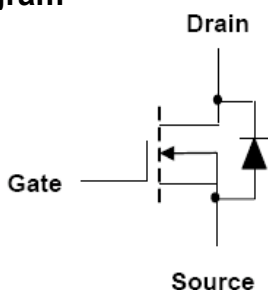
$R_{DS(on)}, V_{GS} @ 10V, I_{DS} @ 10A = 13.5m\Omega$

$R_{DS(on)}, V_{GS} @ 4.5V, I_{DS} @ 8A = 20m\Omega$

Features

- ✧ Advanced trench process technology
- ✧ High Density Cell Design for Ultra Low On-Resistance
- ✧ Fully Characterized Avalanche Voltage and Current

Block Diagram



Ordering Information

| Part No. | Packing | Package |
|-----------|----------------------------------|---------|
| TSM4410CS | Tape & Reel (2,500pcs / Reel) | SOP-8 |

Absolute Maximum Rating ($T_A = 25^\circ C$ unless otherwise noted)

| Parameter | Symbol | Limit | Unit |
|--------------------------------------------------|----------------|--------------------|------------|
| Drain-Source Voltage | V_{DS} | 25 | V |
| Gate-Source Voltage | V_{GS} | ± 20 | V |
| Continuous Drain Current | I_D | 10 | A |
| Pulsed Drain Current | I_{DM} | 50 | |
| Maximum Power Dissipation | P_D | $T_A = 25^\circ C$ | 2 |
| | | $T_A = 70^\circ C$ | 1.3 |
| Operating Junction Temperature | T_J | +150 | $^\circ C$ |
| Operating Junction and Storage Temperature Range | T_J, T_{STG} | -55 to +150 | $^\circ C$ |

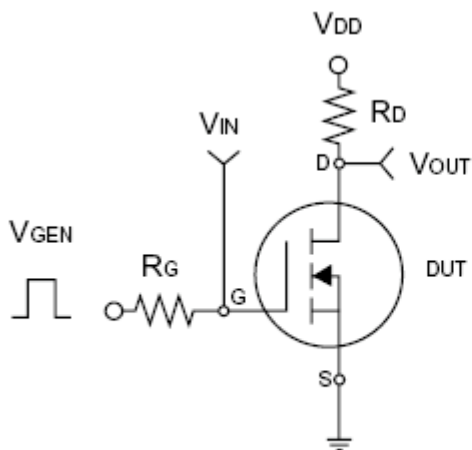
Thermal Performance

| Parameter | Symbol | Limit | Unit |
|------------------------------------------------------|-----------------|-------|--------------|
| Junction-to-case Thermal Resistance | $R_{\theta jc}$ | 2.2 | $^\circ C/W$ |
| Junction to Ambient Thermal Resistance (PCB mounted) | $R_{\theta ja}$ | 50 | |

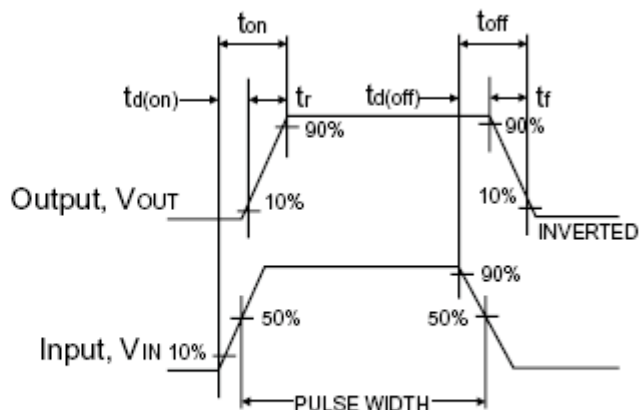
Note: 1. Maximum DC current limited by the package
 2. 1-in² 2oz Cu PCB board

| Electrical Characteristics | | | | | | |
|---------------------------------------------------|---------------------------------------------------------------------------------------------|--------------|-----|--------|-----------|---------------|
| $T_J = 25^\circ\text{C}$, unless otherwise noted | | | | | | |
| Parameter | Conditions | Symbol | Min | Typ | Max | Unit |
| Static | | | | | | |
| Drain-Source Breakdown Voltage | $V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$ | BV_{DSS} | 25 | -- | -- | V |
| Drain-Source On-State Resistance | $V_{GS} = 10\text{V}, I_D = 10\text{A}$ | $R_{DS(ON)}$ | -- | 11 | 13.5 | m Ω |
| | $V_{GS} = 4.5\text{V}, I_D = 5\text{A}$ | $R_{DS(ON)}$ | -- | 16.5 | 20 | m Ω |
| Gate Threshold Voltage | $V_{DS} = V_{GS}, I_D = 250\mu\text{A}$ | $V_{GS(TH)}$ | 1.0 | -- | 3.0 | V |
| Zero Gate Voltage Drain Current | $V_{DS} = 25\text{V}, V_{GS} = 0\text{V}$ | I_{DSS} | -- | -- | 1.0 | μA |
| Gate Body Leakage | $V_{GS} = \pm 20\text{V}, V_{DS} = 0\text{V}$ | I_{GSS} | -- | -- | ± 100 | nA |
| Gate Resistance | $f = 1\text{MHz}$ | R_g | -- | 1.35 | -- | Ω |
| Forward Transconductance | $V_{DS} = 15\text{V}, I_D = 10\text{A}$ | g_{fs} | -- | 25 | -- | S |
| Dynamic | | | | | | |
| Total Gate Charge | $V_{DS} = 15\text{V}, I_D = 10\text{A}, V_{GS} = 5\text{V}$ | Q_g | -- | 7.56 | -- | nC |
| Gate-Source Charge | | Q_{gs} | -- | 2.74 | -- | |
| Gate-Drain Charge | | Q_{gd} | -- | 2.22 | -- | |
| Turn-On Delay Time | $V_{DD} = 15\text{V}, R_L = 25\Omega, I_D = 1\text{A}, V_{GEN} = 10\text{V}, R_G = 6\Omega$ | $t_{d(on)}$ | -- | 6.81 | -- | nS |
| Turn-On Rise Time | | t_r | -- | 1.8 | -- | |
| Turn-Off Delay Time | | $t_{d(off)}$ | -- | 20.37 | -- | |
| Turn-Off Fall Time | | t_f | -- | 3.42 | -- | |
| Input Capacitance | $V_{DS} = 15\text{V}, V_{GS} = 0\text{V}, f = 1.0\text{MHz}$ | C_{iss} | -- | 1046.7 | -- | pF |
| Output Capacitance | | C_{oss} | -- | 148.75 | -- | |
| Reverse Transfer Capacitance | | C_{rss} | -- | 78.26 | -- | |
| Source-Drain Diode | | | | | | |
| Max. Diode Forward Current | | I_S | -- | -- | 10 | A |
| Diode Forward Voltage | $I_S = 2.3\text{A}, V_{GS} = 0\text{V}$ | V_{SD} | -- | 0.85 | 1.3 | V |

Note: 1. pulse test: pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$
 2. Negligible, Dominated by circuit inductance.

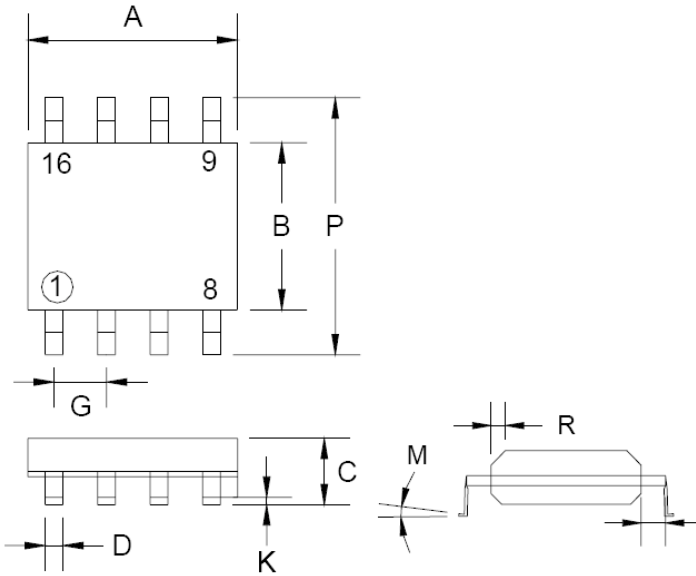


Switching Test Circuit



Switchin Waveforms

SOP-8 Mechanical Drawing



| SOP-8 DIMENSION | | | | |
|-----------------|-------------|------|------------|-------|
| DIM | MILLIMETERS | | INCHES | |
| | MIN | MAX | MIN | MAX |
| A | 4.80 | 5.00 | 0.189 | 0.196 |
| B | 3.80 | 4.00 | 0.150 | 0.157 |
| C | 1.35 | 1.75 | 0.054 | 0.068 |
| D | 0.35 | 0.49 | 0.014 | 0.019 |
| F | 0.40 | 1.25 | 0.016 | 0.049 |
| G | 1.27 (typ) | | 0.05 (typ) | |
| K | 0.10 | 0.25 | 0.004 | 0.009 |
| M | 0° | 7° | 0° | 7° |
| P | 5.80 | 6.20 | 0.229 | 0.244 |
| R | 0.25 | 0.50 | 0.010 | 0.019 |